TOSHIBA Bi-CMOS Integrated Circuit Silicon Monolithic

# **TB62717FG**

## 24 Bit Constant Current Drivers (3 × 8 Bit Shift Register & Latch)

The TB62717FG are specifically designed constant current driver for LED & LED DISPLAY.

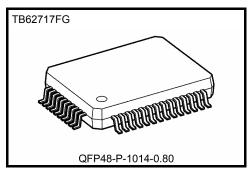
This constant-current output-circuits is able to set up at an external resistor.

This  $\operatorname{IC}$  is monolithic integrated circuit designed to be used together with Bi-CMOS process.

The devices builds in three block composed by the shift register circuit of eight bits, the latch-circuit of eight bits, the AND gate circuit of eight bits and the constant-current output circuits of eight bits.

This device has a SERIAL-IN terminal and a SERIAL-OUT terminal three blocks to each, and has a CLOCK terminal and a LATCH terminal three blocks to the commonness.

The TB62717FG complies with RoHS regulation.



Weight QFP48-P-1014-0.80: 0.83 g (typ.)

#### **Features**

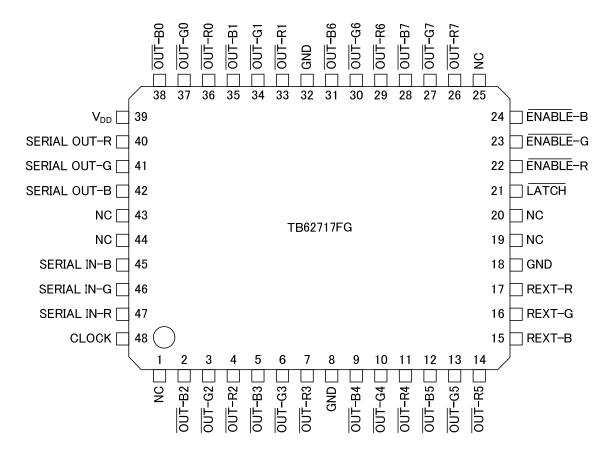
- Constant current output
  - : Able to set up at an external resistor for 2 to 50 mA.
- Schmitt triggered input
- · Recommended operating condition
  - Maximum clock Frequency
    - :  $f_{CLK} = 10.0 MHz$  (cascade connected)
  - IC supply voltage:  $V_{DD} = 4.5$  to 5.5 V
  - Output voltage: Vout = 0.4 to 17 V
  - Operating temperature:  $T_{opr} = -40 \text{ to } 85^{\circ}\text{C}$

## **Constant Output Current Matching**

Output-GND Voltage	Current Matching	Output Current			
≥0.4 V	±6.0%	50 mA			

- 5 V CMOS Compatible Input
- Package: QFP48-P-1014-0.80

## Pin Connection (top view)

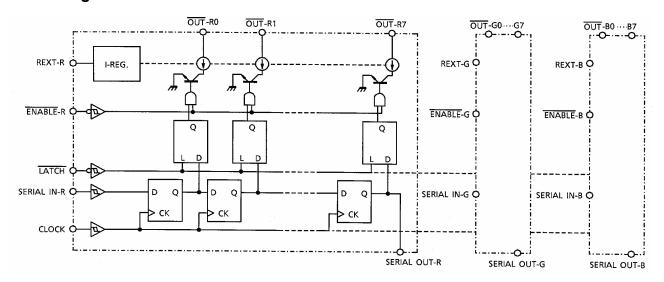


2 2008-01-15

TB62717FG



## **Block Diagram**



Note: I<sub>OUT</sub> = 30 mA/bit (max) in 24 bit output activate

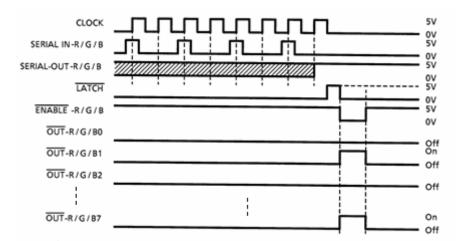
## **Truth Table**

CLOCK	LATCH	ENABLE R/G/B	SERIAL-IN R/G/B	OUT - ··· OUT - ··· OUT - R/G/B0 R/G/B3 R/G/B7	SERIAL-OUT R/G/B
UP	Н	L	D <sub>n</sub>	$D_{n} \cdots D_{n-3} \cdots D_{n-7}$	D <sub>n-7</sub>
UP	L	L	D <sub>n+1</sub>	No Change	D <sub>n-6</sub>
DOWN	Н	L	D <sub>n+1</sub>	$D_{n+1} \cdots D_{n-2} \cdots D_{n-6}$	D <sub>n-6</sub>
_	Х	L	D <sub>n+2</sub>	No Change	D <sub>n-6</sub>
_	Х	Н	D <sub>n+3</sub>	All Off	D <sub>n-6</sub>

Note:  $\overline{\text{OUT}} - R/G/B0$  to 7 = on in case of Dn = H level and  $\overline{\text{OUT}} - R/G/B0$  to 7 = off in case of Dn = L level. A resistor is connected with R-EXT and GND accompanied with outside, and it is necessary that a correct power supply voltage is supplied.

3

## **Timing Diagram**



Note:  $\overline{\text{LATCH}}$  is level sensitive, not rising edges sensitive and not synchronous CLOCK.

Input of  $\overline{\text{LATCH}}$  -terminal to "H" level, data passes latches, and input to "L" level, data hold latches.

Input of  $\overline{\text{ENABLE}}$  -terminal to "H" level, all output do off.

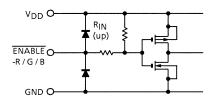
# **Terminal Explanation**

Numbers	Nama	Forder office				
FG	Name	Explanation				
36 to 38	OUT -R/G/B0	This terminal is the constant-current output of the 1st bit of each block. An output terminal is high-active in the input data.				
33 to 35	OUT -R/G/B1	This terminal is the constant-current output of the 2nd bit of each block. An output terminal is high-active in the input data.				
2 to 4	OUT -R/G/B2	This terminal is the constant-current output of the 3rd bit of each block. An output terminal is high-active in the input data.				
5 to 7	OUT -R/G/B3	This terminal is the constant-current output of the 4th bit of each block. An output terminal is high-active in the input data.				
9 to 11	OUT -R/G/B4	This terminal is the constant–current output of the 5th bit of each block. An output terminal is high–active in the input data.				
12 to 14	OUT -R/G/B5	This terminal is the constant–current output of the 6th bit of each block. An output terminal is high–active in the input data.				
29 to 31	OUT -R/G/B6	This terminal is the constant-current output of the 7th bit of each block. An output terminal is high-active in the input data.				
26 to 28	OUT -R/G/B7	This terminal is the constant-current output of the 8th bit of each block. An output terminal is high-active in the input data.				
8, 18, 32	GND	These three terminals are GND terminals. We recommend that it is grounded (this terminal all).				
45 to 47	SERIAL IN-R/G/B	This terminal is a serial-data input of each block.				
48	CLOCK	This terminal is the clock signal input which is common to each block.				
21	LATCH	This terminal is latch signal input. This terminal is a level latch. Therefore, input data are held while input of a L level is being maintained. It only passes through the data on the output side in the case of the H level.				
22 to 24	ENABLE -R/G/B	This terminal is output control signal input. When input of a L level is maintained, an output terminal drives this terminal corresponding to the input data. Output is made a non-drive independently with the input data in the case of the H level.				
15 to 17	REXT- R/G/B	This terminal is for the resistance connection which the output electric current value of each block is set up to. Resistance with the outside is connected between this terminal and GND. Output electric current is set up in the value corresponding to the re				
39	V <sub>DD</sub>	This terminal is input of a power supply voltage 5 V.				
40 to 42	SERIAL OUT - R/G/B	This terminal is a serial-data output of each block.				
1,19 to 20 25,43 to 44	NC	terminal is a unconnection.				

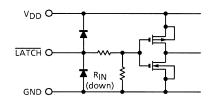
5 2008-01-15

## **Equivalent Circuit About the Input and Output Terminal**

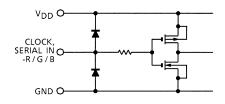
## 1. The terminal of the ENABLE -R/G/B



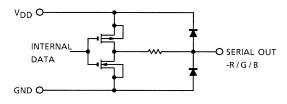
## 2. The terminal of the $\overline{LATCH}$



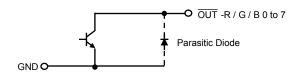
# 3. The terminal of the CLOCK and SERIAL IN-R/G/B



## 4. The terminal of the SERIAL OUT-R/G/B



## 5. The terminal of the OUT - R/G/B0 to 7



## Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{DD}$	+7.0	V
Input voltage	V <sub>IN</sub>	−0.4 to V <sub>DD</sub> + 0.4	V
Output current	lout	+50	mA
Output voltage	V <sub>OUT</sub>	−0.5 to +17.0	V
Clock frequency	fcLK	15	MHz
GND terminal current (Note 1)	I <sub>GND</sub>	1200	mA
Power dissipation (Note 2)	PD	1.38 (ON PCB)/0.86 (FREE AIR)	W
Thermal resistance (Note 2)	R <sub>th (j−a)</sub>	90 (On PCB)/145 (FREE AIR)	°C/W
Operating temperature	T <sub>opr</sub>	-40 to +85	°C
Storage temperature	T <sub>stg</sub>	−55 to +150	°C

Note 1: Use all GND-terminals.

Note 2: Ambient temperature delayed the above 25°C with 11.1 mW/°C in on PCB

(Glass Epoxy PCB  $50 \times 50 \times 1.6$  mm Cu 36%).

## Recommended Operating Condition (Ta = 25°C unless otherwise noted)

Characteristics	Symbol	Condition	Min	Тур.	max	Unit
Supply voltage	$V_{DD}$	_	4.5	5.0	5.5	V
Output voltage	V <sub>OUT</sub>	_	0.4	_	15.0	V
	lout	DC 1 circuit	_	_	35	mA
Output current	ГОН	SERIAL-OUT	_	_	-1.0	
	l <sub>OL</sub>	SERIAL-OUT	_	_	1.0	
Input voltage	V <sub>IH</sub>	_	0.7 V <sub>DD</sub>	_	V <sub>DD</sub> + 0.3	· V
	V <sub>IL</sub>	_	-0.3	_	0.3 V <sub>DD</sub>	
CLOCK pulse width	t <sub>wCLK</sub>	V <sub>DD</sub> = 4.5 to 5.5V, CLOCK = "H" or "L"	50	_	_	ns
LATCH pulse width	t <sub>w/LATCH</sub>			_	_	ns
ENABLE pulse width	t <sub>w/EN</sub>		4500	_	_	ns
Set-up time for DATA	t <sub>setup(D)</sub>	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	60	_	_	ns
Hold time for DATA	t <sub>hold(D)</sub>	V <sub>DD</sub> = 4.5 to 5.5 V	20	_	_	ns
Set-up time for LATCH	t <sub>setup(L)</sub>		100	_	_	ns
Hold time for LATCH	t <sub>hold(L)</sub>		60	_	_	ns
Clock frequency	f <sub>CLK</sub>	V <sub>DD</sub> = 4.5 to 5.5V, Cascade operation	_	_	10.0	MHz
Power dissipation	PD	Ta = 85°C, On PCB	_	_	0.71	W

## **Electrical Characteristics (Ta = 25°C unless otherwise noted)**

Characteristics		Symbol	Test Circuit	Con	dition	Min	Тур.	Max	Unit
Input	"H" level	V <sub>IH</sub>	_	Ta = -40 to 85°C		0.7 V <sub>DD</sub>		$V_{DD}$	V
voltage	"L" level	$V_{IL}$				GND	_	0.3 V <sub>DD</sub>	
Output leakage curren	t	Іон	5	V <sub>OH</sub> = 15.0 V				10	μΑ
Output	SOUT-R/G/B	$V_{OL}$	1	$I_{OL} = 1.0 \text{ mA}$				0.4	V
voltage	3001-17/0/15	V <sub>OH</sub>	'	$I_{OL} = -1.0 \text{ mA}$		4.6			V
Output current	Output current			V <sub>CE</sub> = 0.4 V		25.5	30.0	34.5	mA
	Current skew	$\Delta_{OL}$	5	$I_{OL} = 30 \text{ mA},$ $V_{CE} = 0.4 \text{ V}$	REXT = 660 Ω		±1.5	±6.0	%
Supply voltage regulat	tion	%/V <sub>DD</sub>	5	R <sub>EXT</sub> = 660 Ω	Ta = -40 to 85°C		1.5	5.0	%/V
Pull-up resistor	Pull-up resistor		3	_		150	300	600	kΩ
Pull-down resistor		R <sub>IN (down)</sub>	2	_		150	300	600	kΩ
	"OFF"	I <sub>DD</sub> (off) 1	4	R <sub>EXT</sub> = OPEN	All output off	_	1.2	2.4	
Supply current	OFF	I <sub>DD (off) 2</sub>		$R_{EXT} = 660 \Omega$ All output off	7.0	12.0	16.0	mA	
3	"ON"	I <sub>DD (on) 1</sub>			All output on	15.0	28.0	40.0	

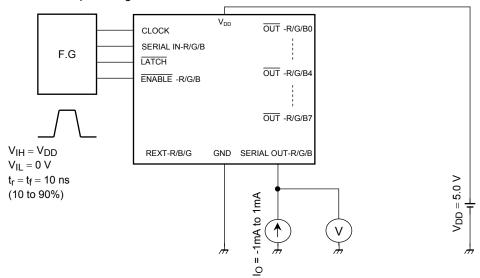
## Switching Characteristics (Ta = 25°C unless otherwise noted)

Characteristics		Symbol	Test Circuit	Condition	Min	Тур.	Max	Unit
	CLK- OUTn	t <sub>pLH1</sub>		$V_{DD} = 5.0 \text{ V} \\ V_{CE} = 0.4 \text{ V} \\ V_{IH} = V_{DD} \\ 6  V_{IL} = GND \\ REXT = 660 \Omega \\ V_{L} = 3.0 \text{ V} \\ C_{L} = 10.5 \text{ pF}$	_	1200	1500	ns
Propagation delay time	LATCH - OUTn	t <sub>pLH2</sub>			_	1200	1500	
("L" to "H")	EN - OUTn	t <sub>pLH3</sub>			_	1200	1500	
	CLK-SOUT	t <sub>pLH4</sub>			_	30	70	
	CLK- OUTn	t <sub>pHL1</sub>	6		_	700	1000	
Propagation delay time	LATCH - OUTn	t <sub>pHL2</sub>			_	700	1000	
("H" to "L")	EN - OUTn	t <sub>pHL3</sub>			_	700	1000	
	CLK-SOUT	t <sub>pHL4</sub>			_	30	70	
Maximum CLOCK rise time		t <sub>r</sub>				_	10	116
Maximum CLOCK fall time		t <sub>f</sub>			_	_	10	μS
Output rise time		t <sub>or</sub>			300	600	1000	ns
Output fall time		t <sub>of</sub>			150	300	600	113

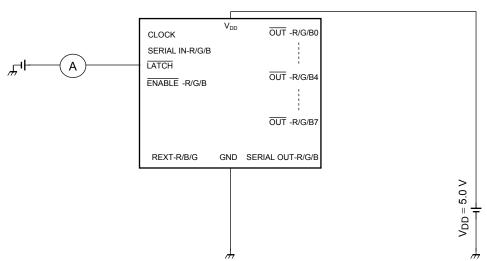


## **Test Circuit**

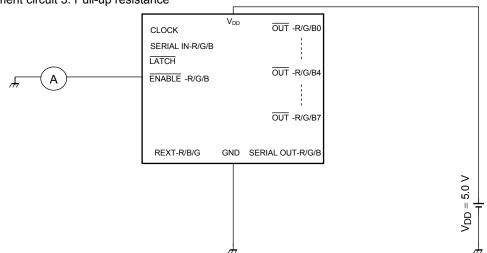
Measurement circuit 1: Output voltage



Measurement circuit 2: Pull-down resistance



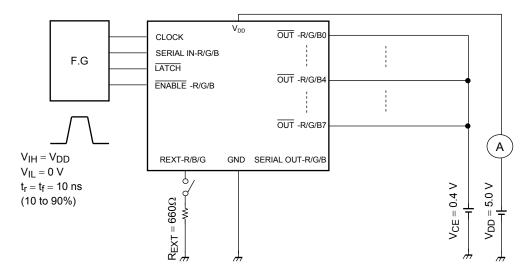
Measurement circuit 3: Pull-up resistance



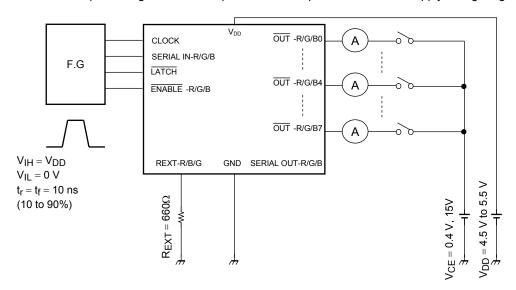
9

2008-01-15

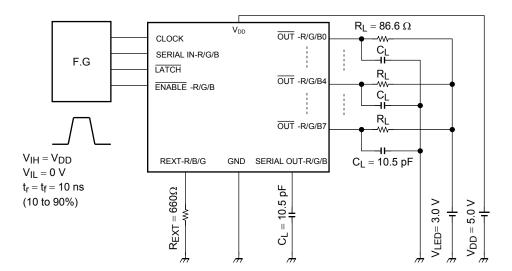
Measurement circuit 4: Supply current



Measurement circuit 5: Output leakage current / Output current / Output current skew / Supply voltage regulation



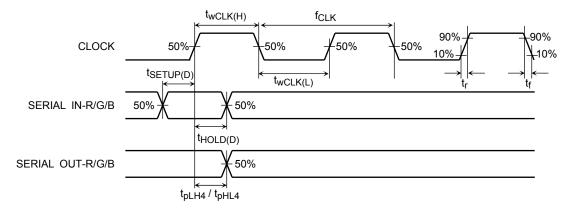
Measurement circuit 6: Switching Characteristics



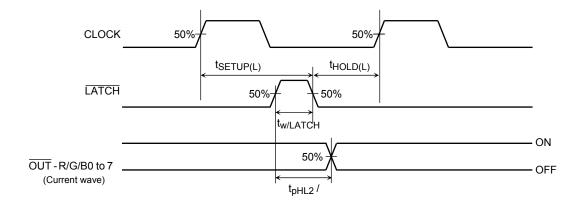


## **Timing Waveform**

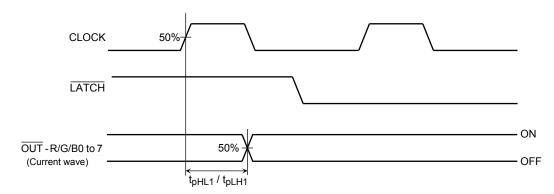
## 1. CLOCK, SERIAL IN-R/G/B, SERIAL OUT-R/G/B



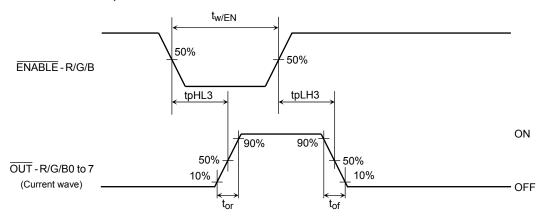
## 2. CLOCK, LATCH, OUT - R/G/B0 to 7

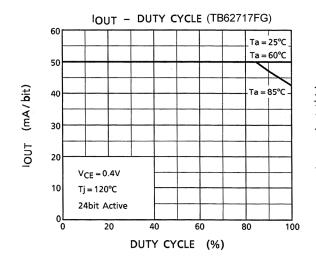


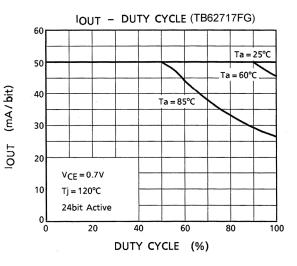
## 3. CLOCK, LATCH, OUT -R/G/B0 to 7

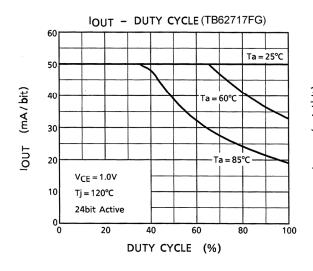


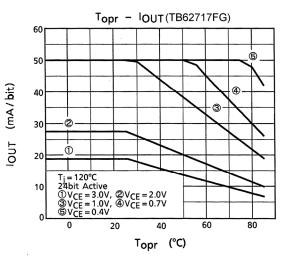
## 4. ENABLE - R/G/B, OUT - R/G/B0 to 7

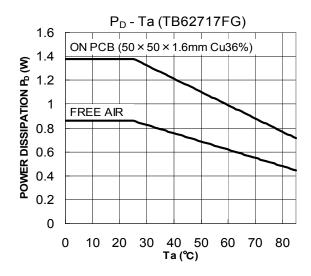




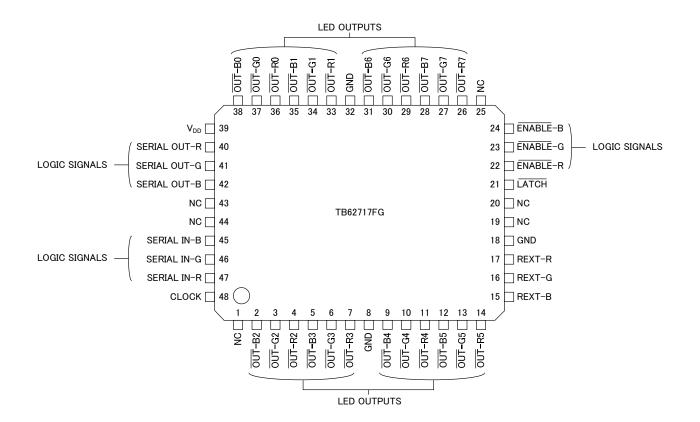








## I/O Layout Image



## **Output Current - Resistor**

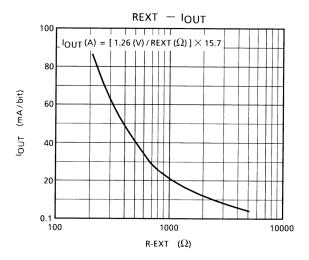


Figure 1

13

The bottom figure shows an application circuit.

For best results, this IC should be operated with  $V_O = 0.4V$  to 0.7 V.

$$V_O = V_{LED} - V_f (LED) - V_{CE} (PNP Tr)$$

When V<sub>LED</sub> is high and the V<sub>f</sub> of the LED is low.

Vo is also high, the increase in power dissipation may in turn adversely affect the IC's output current.

In this case, reduce the voltage by connecting an external resistor.

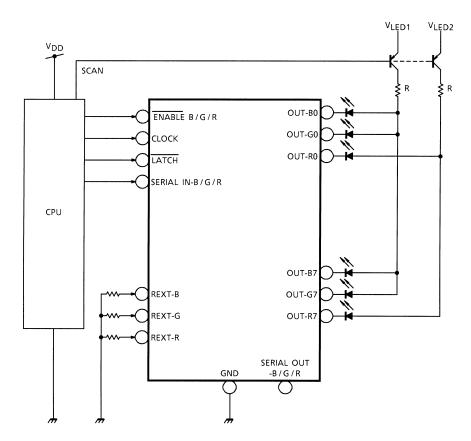
In this way the IC's output current can be stabilized.

$$R = \frac{V_{LED}(MIN) - V_f(MAX) - V_{CE(PNPTr)}(MAX) - V_O(SetValue)}{I_O(MAX) \times BIT(MAX)}$$

Operation may become unstable due to the electromagnetic interference caused by the wiring and other phenomena. To counter this, it is recommended that the IC be situated as close as possible to the LED module.

There is only one GND terminal on this device when the inductance in the GND line and the resistor are large, the device may malfunction due to the GND noise when output switching by the circuit board pattern and wiring. So we would like you to pay attention to pattern layout to minimize inductance.

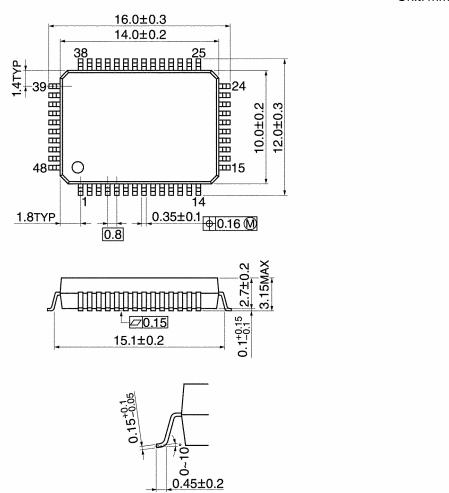
## **Applied circuit**



14

## **Package Dimensions**

QFP48-P-1014-0.80 Unit: mm



Weight: 0.83 g (typ.)

#### **Notes on Contents**

## 1. Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

#### 2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

#### 3. Timing Charts

Timing charts may be simplified for explanatory purposes.

#### 4. Application Circuits

The application circuits shown in this document are provided for reference purposes only.

Thorough evaluation is required, especially at the mass production design stage.

Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.

#### 5. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

## IC Usage Considerations

#### **Notes on Handling of ICs**

- (1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.
  Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
- (2) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- (3) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition.

  Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- (4) Do not insert devices in the wrong orientation or incorrectly. Make sure that the positive and negative terminals of power supplies are connected properly. Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion. In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.
- (5) Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator.

  If there is a large amount of leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage to a speaker directly.

#### Points to Remember on Handling of ICs

(1) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

(2) Back-EMF

When a motor rotates in the reverse direction, stops or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

About solderability, following conditions were confirmed

- · Solderability
  - (1) Use of Sn-37Pb solder Bath
    - · solder bath temperature = 230°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux
  - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
    - · solder bath temperature = 245°C
    - · dipping time = 5 seconds
    - the number of times = once
    - · use of R-type flux

#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No
  responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
  may result from its use. No license is granted by implication or otherwise under any patents or other rights of
  TOSHIBA or the third parties.
- Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.